

Vishay Semiconductors

Silicon NPN Phototransistor



DESCRIPTION

VEMT2000X01 series are silicon NPN epitaxial planar phototransistors with daylight blocking filter in a miniature, black dome lens package for surface mounting. Filter bandwidth is matched with 830 nm to 950 nm IR emitters.

FEATURES

- Package type: surface mount
- Package form: GW, RGW
- Dimensions (L x W x H in mm): 2.3 x 2.3 x 2.8
- AEC-Q101 qualified
- · High radiant sensitivity
- Daylight blocking filter matched with 830 nm to 950 nm IR emitters
- Fast response times
- Angle of half sensitivity: $\phi = \pm 15^{\circ}$
- Package matched with IR emitter series VSMB2000X01
- Floor life: 4 weeks, MSL 2a, acc. J-STD-020
- Lead (Pb)-free reflow soldering
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition
- Find out more about Vishay's Automotive Grade Product requirements at: <u>www.vishay.com/applications</u>

APPLICATIONS

- · Detector in automotive applications
- Photo interrupters
- Miniature switches
- Counters
- · Encoders
- · Position sensors

PRODUCT SUMMARY				
COMPONENT	I _{ca} (mA)	φ (deg)	λ _{0.5} (nm)	
VEMT2000X01	6	± 15	790 to 970	
VEMT2020X01	6	± 15	790 to 970	

Note

Test condition see table "Basic Characteristics"

ORDERING INFORMATION				
ORDERING CODE	PACKAGING	AGING REMARKS PACK		
VEMT2000X01	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Reverse gullwing	
VEMT2020X01	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Gullwing	

Note

MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Collector emitter voltage		V _{CEO}	20	V
Emitter collector voltage		V _{ECO}	7	V
Collector current		Ι _C	50	mA
Power power dissipation	$T_{amb} \le 75 \ ^{\circ}C$	Pv	100	mW



RoHS COMPLIANT

HALOGEN

FREE

AUTOMOTIVE

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ABSOLUTE MAXIMUM RATINGS				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Junction temperature		Тj	100	°C
Operating temperature range		T _{amb}	- 40 to + 100	°C
Storage temperature range		T _{stg}	- 40 to + 100	°C
Soldering temperature	Acc. reflow profile fig. 7	T _{sd}	260	°C
Thermal resistance junction/ambient	Acc. J-STD-051	R _{thJA}	250	K/W

Note

 $T_{amb} = 25$ °C, unless otherwise specified

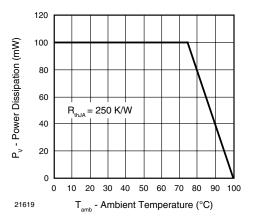


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

BASIC CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Collector emitter breakdown voltage	I _C = 0.1 mA	V _{CEO}	20			V
Collector dark current	$V_{CE} = 5 V, E = 0$	I _{CEO}		1	100	nA
Collector emitter capacitance	$V_{CE} = 0 V, f = 1 MHz, E = 0$	C _{CEO}		25		pF
Collector light current	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}, \\ V_{CE} = 5 \text{ V}$	I _{ca}	3	6	9	mA
Angle of half sensitivity		φ		± 15		deg
Wavelength of peak sensitivity		λρ		860		nm
Range of spectral bandwidth		λ _{0.5}		790 to 970		nm
Collector emitter saturation voltage	I _C = 0.05 mA	V _{CEsat}			0.4	V

Note

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BASIC CHARACTERISTICS

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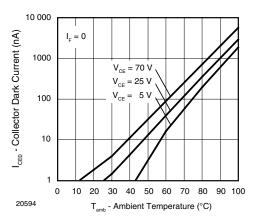


Fig. 2 - Collector Dark Current vs. Ambient Temperature

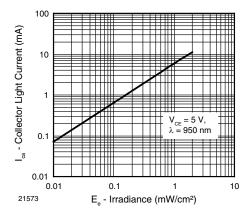


Fig. 3 - Collector Light Current vs. Irradiance

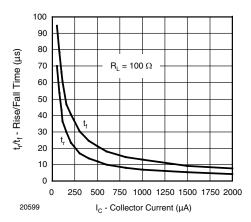


Fig. 4 - Rise/Fall Time vs. Collector Current

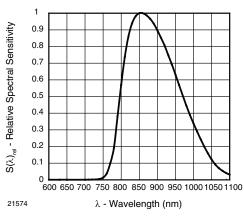


Fig. 5 - Relative Spectral Sensitivity vs. Wavelength

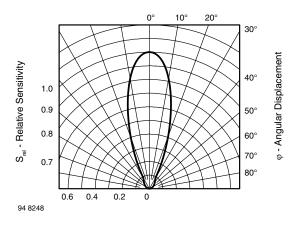


Fig. 6 - Relative Radiant Sensitivity vs. Angular Displacement

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REFLOW SOLDER PROFILE

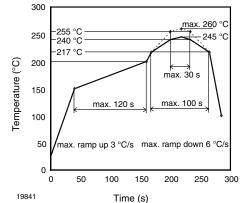


Fig. 7 - Lead (Pb)-free Reflow Solder Profile acc. J-STD-020

DRYPACK

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

FLOOR LIFE

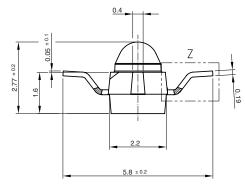
Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label: Floor life: 4 weeks Conditions: $T_{amb} < 30$ °C, RH < 60 % Moisture sensitivity level 2a, acc. to J-STD-020.

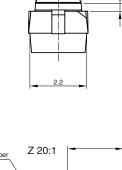
DRYING

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or label. Devices taped on reel dry using recommended conditions 192 h at 40 °C (+ 5 °C), RH < 5 %.

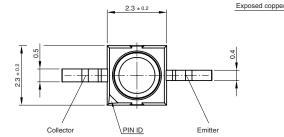
0.3

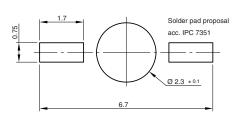
PACKAGE DIMENSIONS VEMT2000X01 in millimeters



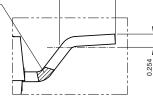


Ø 1.8 ± 0.1





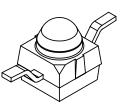
Drawing-No.: 6.544-5391.01-4 Issue: 1; 26.09.08 21570





1.1 ± 0.

Not indicated to lerances ±0.1

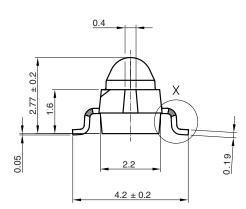


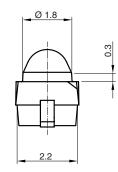


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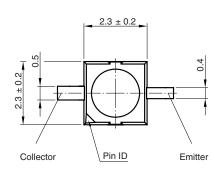
PACKAGE DIMENSIONS VEMT2020X01 in millimeters

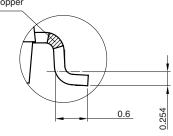




Exposed copper

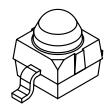
X 20:1

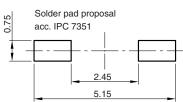






Not indicated tolerances ± 0.1





Drawing-No.: 6.544-5383.01-4 Issue: 4; 28.01.09 21569

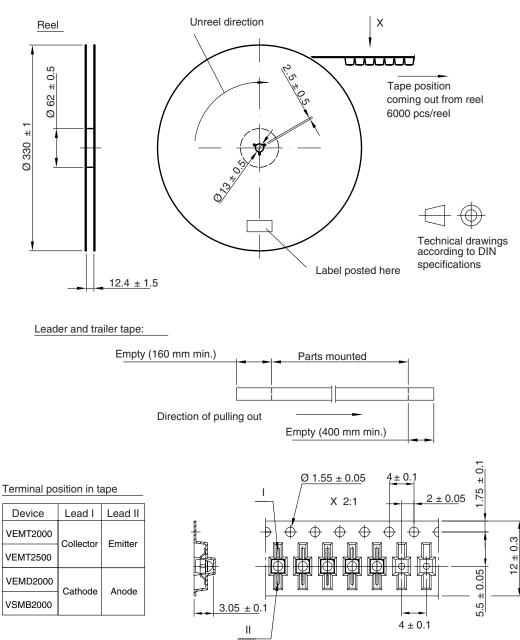
Document Number: 81595 Rev. 1.1, 23-Jul-09

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TAPE AND REEL DIMENSIONS VEMT2000X01 in millimeters



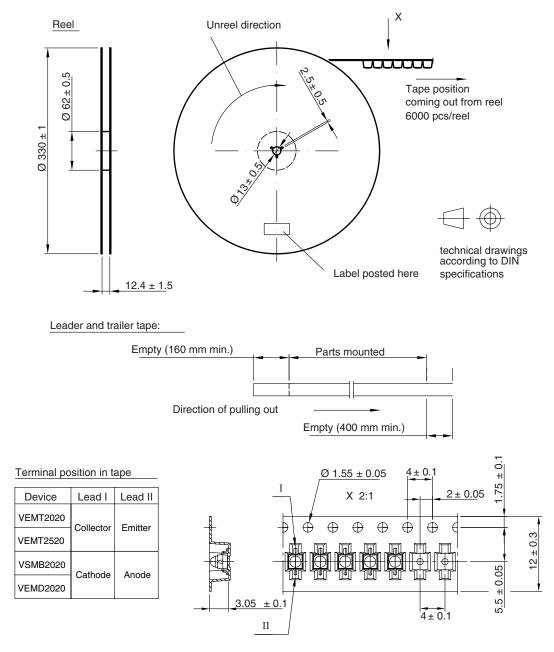
Drawing-No.: 9.800-5100.01-4 Issue: X; 29.04.09 21572



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TAPE AND REEL DIMENSIONS VEMT2020X01 in millimeters



Drawing-No.: 9.800-5091.01-4 Issue: X; 29.04.09 21571



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